

P-Channel 30V(D-S) MOSFET

| Product summary | | |
|--|------|-----------|
| V_{DS} | -30 | V |
| $R_{DS(ON)}$ (at $V_{GS}=-10V$) Typ. | 40 | $m\Omega$ |
| $R_{DS(ON)}$ (at $V_{GS}=-4.5V$) Typ. | 53 | $m\Omega$ |
| $I_D(T_A=25^\circ C)$ | -4.1 | A |

Features

- Trench Power LV MOSFET technology
- High Speed switching
- High density cell design for Low $R_{DS(ON)}$

Applications

- Power management
- Load switch

Pin Configuration



Packing Information

| Device | Reel Size | Quantity(Min. Package) |
|----------|-----------|------------------------|
| ECG3407A | 7" | 3000pcs |

Absolute Maximum Ratings (at $T_A=25^\circ C$ Unless Otherwise Noted)

| Symbol | Parameter | Rating | Units |
|----------------|---|------------------|-------|
| V_{DS} | Drain-Source Voltage | -30 | V |
| V_{GS} | Gate-Source Voltage | ± 20 | V |
| I_D | Continuous Drain Current at $V_{GS}=-10V$ | $T_A=25^\circ C$ | A |
| | | $T_A=70^\circ C$ | A |
| I_{DM} | Pulse Drain Current Tested ^A | -15 | A |
| P_D | Power Dissipation | $T_A=25^\circ C$ | W |
| T_J, T_{STG} | Junction and Storage Temperature Range | -55 to +150 | °C |

Thermal Characteristics

| Symbol | Parameter | Typical | Units |
|-----------------|---|---------|-------|
| $R_{\theta JA}$ | Thermal Resistance-Junction to ambient ^B | 125 | °C/W |

Electrical Characteristics (at $T_J = 25^\circ\text{C}$ Unless Otherwise Noted)

| Symbol | Parameter | Condition | Min. | Typ. | Max. | Units |
|-----------------------------|----------------------------------|---|------|------|-----------|------------------|
| Static Parameters | | | | | | |
| BV_{DSS} | Drain-Source Breakdown Voltage | $V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$ | -30 | -- | -- | V |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{\text{DS}}=-30\text{V}, V_{\text{GS}}=0\text{V}$ | -- | -- | -1 | μA |
| I_{GSS} | Gate-Body Leakage Current | $V_{\text{DS}}=0\text{V}, V_{\text{GS}}=\pm 20\text{V}$ | -- | -- | ± 100 | nA |
| $V_{\text{GS}(\text{th})}$ | Gate Threshold Voltage | $V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$ | -1.0 | -1.5 | -2.4 | V |
| $R_{\text{DS(ON)}}$ | Drain-Source On-State Resistance | $V_{\text{GS}}=-10\text{V}, I_{\text{D}}=-4.1\text{A}$ | -- | 40 | 55 | $\text{m}\Omega$ |
| | | $V_{\text{GS}}=-4.5\text{V}, I_{\text{D}}=-3.5\text{A}$ | -- | 53 | 68 | $\text{m}\Omega$ |
| V_{SD} | Forward Voltage | $I_{\text{SD}}=-4.1\text{A}, V_{\text{GS}}=0\text{V}$ | -- | -- | -1.2 | V |
| Dynamic Parameters | | | | | | |
| C_{iss} | Input Capacitance | $V_{\text{GS}}=0\text{V}, V_{\text{DS}}=-15\text{V}$ $f=1\text{MHz}$ | -- | 584 | -- | pF |
| C_{oss} | Output Capacitance | | -- | 97 | -- | pF |
| C_{rss} | Reverse Transfer Capacitance | | -- | 74 | -- | pF |
| Switching Parameters | | | | | | |
| Q_g | Total Gate Charge | $V_{\text{DS}}=-15\text{V}, I_{\text{D}}=-4.1\text{A}$ $V_{\text{GS}}=-10\text{V}$ | -- | 6.9 | -- | nC |
| Q_{gs} | Gate-Source Charge | | -- | 1.1 | -- | nC |
| Q_{gd} | Gate-Drain Charge | | -- | 1.5 | -- | nC |
| $t_{\text{D(on)}}$ | Turn-on Delay Time | $V_{\text{DD}}=-15\text{V}$ $R_L=15\Omega, I_{\text{D}}=-1\text{A}$, $R_{\text{GEN}}=2.5\Omega$, $V_{\text{GS}}=-10\text{V}$ | -- | 15 | -- | nS |
| t_r | Turn-on Rise Time | | -- | 63 | -- | nS |
| $t_{\text{D(off)}}$ | Turn-off Delay Time | | -- | 19 | -- | nS |
| t_f | Turn-off Fall Time | | -- | 10 | -- | nS |

A. Pulse Test: Pulse Width $\leq 300\text{us}$, Duty cycle $\leq 2\%$.

B. Device mounted on FR-4 PCB, 1 inch x 1 inch x 0.062 inch.

Typical Characteristics

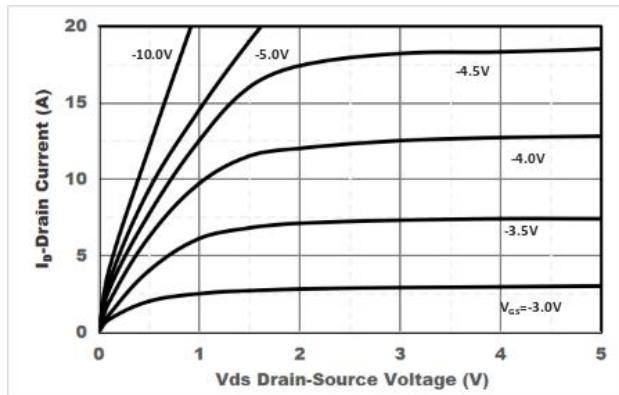


Figure1. Output Characteristics

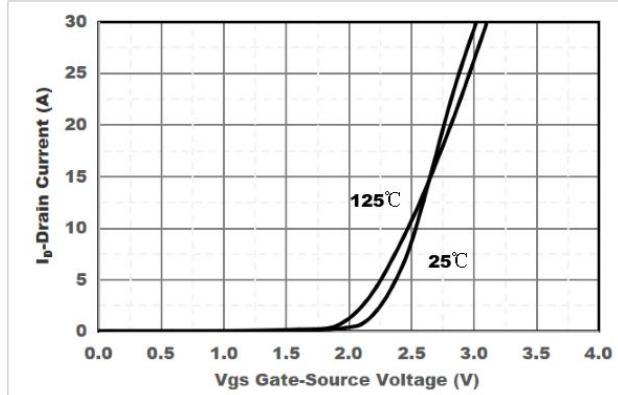


Figure2. Transfer Characteristics

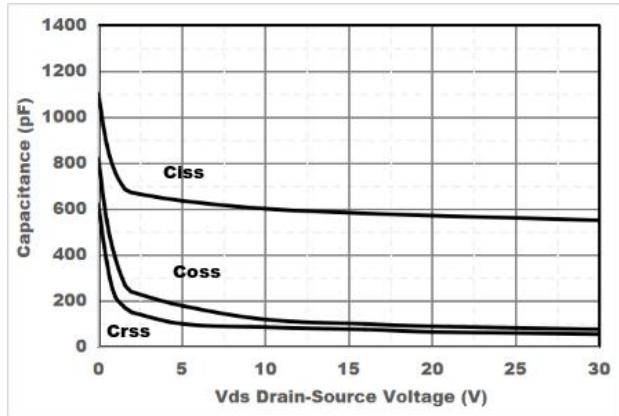


Figure3. Capacitance Characteristics

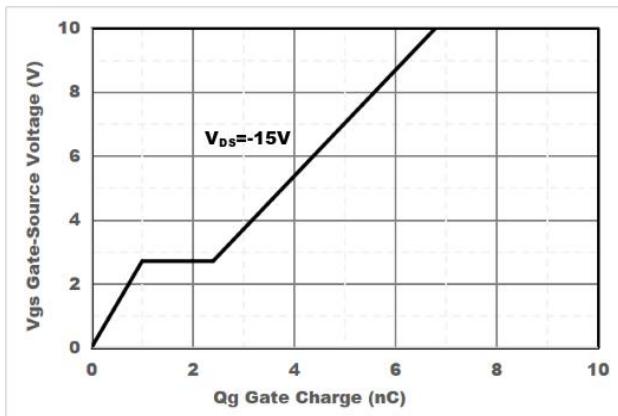


Figure4. Gate Charge

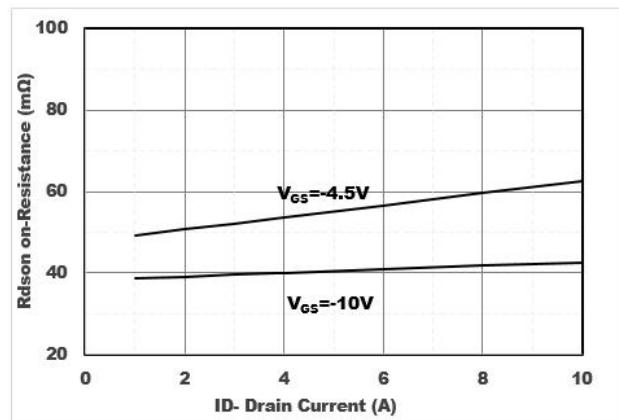


Figure5. Drain-Source on Resistance

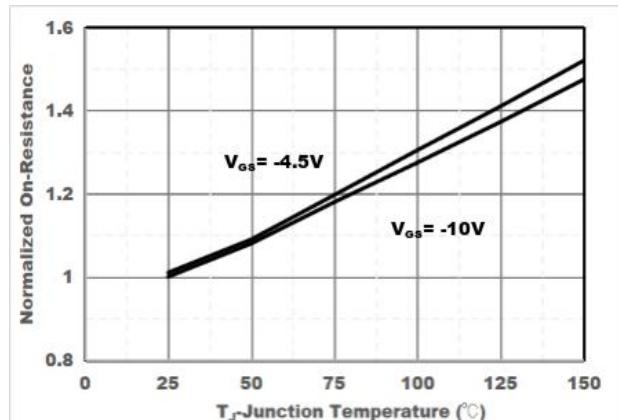


Figure6. Drain-Source on Resistance

Typical Characteristics

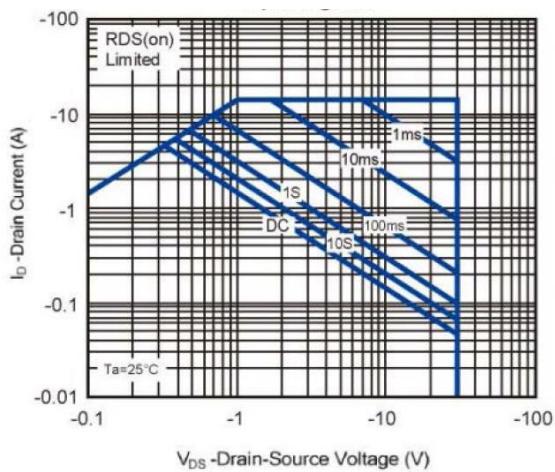


Figure 7. Safe Operation Area

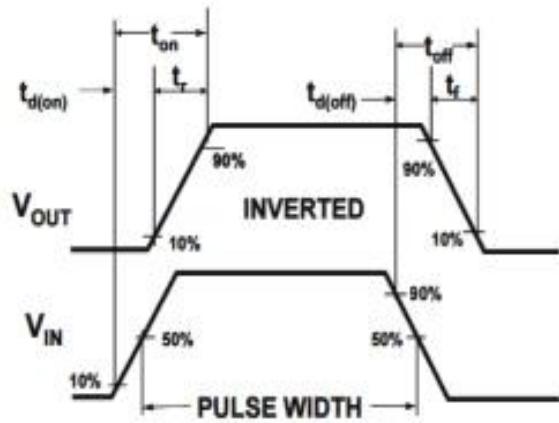
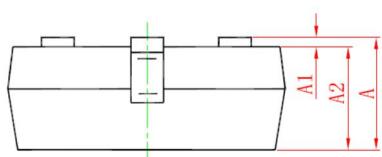
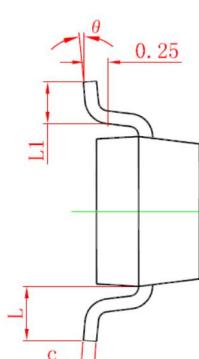
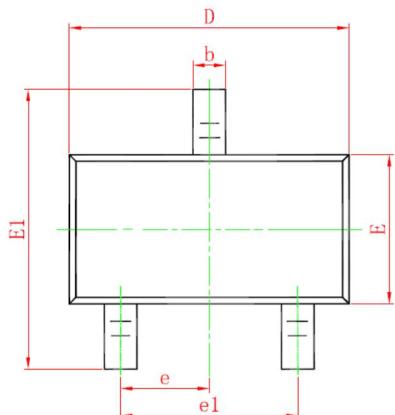


Figure 8. Switching wave

SOT-23 Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|----------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 0.900 | 1.150 | 0.035 | 0.045 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 0.900 | 1.050 | 0.035 | 0.041 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 2.800 | 3.000 | 0.110 | 0.118 |
| E | 1.200 | 1.400 | 0.047 | 0.055 |
| E1 | 2.250 | 2.550 | 0.089 | 0.100 |
| e | 0.950 TYP. | | 0.037 TYP. | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.550 REF. | | 0.022 REF. | |
| L1 | 0.300 | 0.500 | 0.012 | 0.020 |
| θ | 0° | 8° | 0° | 8° |